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Low-Voltage, Dual-Supply, SPDT Analog Switch with Enable

General Description

The MAX4564 is a low-voltage, dual-supply, singlepole/double-throw (SPDT) analog switch designed to operate from dual $\pm 1.8V$ to $\pm 6V$ or single $\pm 1.8V$ to $\pm 12V$ supplies. The low on-resistance (R_{ON} = 40Ω at $\pm 5V$) and low power consumption (5µW) make this part ideal for audio, video, and battery-powered applications. This switch offers low leakage currents (1nA max) and fast switching speeds (t_{ON} = 60ns and t_{OFF} = 40ns at $\pm 5V$, max).

The MAX4564 is available in 8-pin SOT23 and $\mu\text{MAX}^{\textcircled{R}}$ packages.

Applications

Battery-Operated Systems

Audio and Video Switching

Test Equipment

Communications Circuits

Sample-and-Hold Circuits

Communications Systems

Features

- 60Ω max (40Ω, typ) On-Resistance (Ron)
- 3Ω max (0.75Ω, typ) R_{ON} Matching Between Channels
- ♦ 10Ω (max) Ron Flatness
- Low Charge Injection: 3pC (typ)
- Low ±1nA Leakage Current at +25°C
- Fast Switching ton = 60ns (max) toff = 40ns (max)
- Guaranteed Break-Before-Make Switching
- TTL/CMOS-Logic Compatible
- Low Crosstalk: -72dB (1MHz)
- High Off-Isolation: -77dB (1MHz)
- Bandwidth -3dB: >450MHz (typ)
- Available in an 8-Pin SOT23 Package

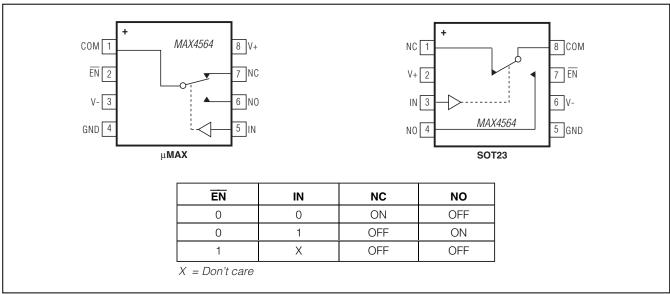
Ordering Information

PART	TEMP RANGE	PIN PACKAGE	TOP MARK
MAX4564EKA+	-40°C to +85°C	8 SOT23	AAEI
MAX4564EUA+	-40°C to +85°C	8 µMAX	_

µMAX is a registered trademark of Maxim Integrated Products, Inc.

+Denotes a lead(Pb)-free/RoHS-compliant package. T = Tape and reel.

Functional Diagrams/Pin Configurations/Truth Table



For pricing, delivery, and ordering information, please contact Maxim Direct at 1-888-629-4642, or visit Maxim's website at www.maximintegrated.com.

Low-Voltage, Dual-Supply, SPDT Analog Switch with Enable

ABSOLUTE MAXIMUM RATINGS

(Voltages Referenced to GND)

MAX4564

V+	
V	
V+ to V	-0.3V to +13V
EN, IN, COM, NC, NO (Note 1) (V-	-0.3V) to (V+ + 0.3V)
Continuous Current (any terminal)	
Peak Current, COM, NC, NO	
(pulsed at 1ms, 10% duty cycle)	±30mA
ESD per Method 3015.7	>2kV

Continuous Power Dissipation ($T_A = +70^{\circ}C$)	
SOT23 (derate 5.6mW/°C above +70°C)	444.4mW
µMAX (derate 4.5mW/°C above +70°C).	362mW
Operating Temperature Range	
MAX4564E_A	40°C to +85°C
Junction Temperature	+150°C
Storage Temperature Range	
Lead Temperature (soldering, 10s)	+300°C
Soldering Temperature (reflow)	

Note 1: Signals on NO, NC, COM, IN, or EN exceeding V+ or V- are clamped by internal diodes. Limit forward-diode current to maximum current rating.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS—±5V Supply

(V+ = +4.5V to +6V, V- = -4.5V to -6V, V_{IH} = +2.4V, V_{IL} = +0.8V, GND = 0, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	ТҮР	MAX	UNITS	
ANALOG SWITCH								
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			V-		V+	V	
On-Resistance	Ron	V+ = +4.5V, V- = -4.5V,	+25°C		40	60	Ω	
On-nesistance	NON	$I_{COM} = 1$ mA; V_{NO} , $V_{NC} = \pm 3.5$ V	E			100	52	
On-Resistance Match Between		V+ = +4.5V, V- = -4.5V,	+25°C		0.75	3	Ω	
Channels (Note 4)	ΔhON	$I_{COM} = 1 \text{mA}; V_{NO}, V_{NC} = \pm 3.5 \text{V}$	E			4		
On-Resistance Flatness	PELAT(ON)	$R_{FLAT(ON)} V_{+} = +4.5V, V_{-} = -4.5V, I_{COM} = 1 \text{ mA}; V_{NO}, V_{NC} = -3.5V, 0, +3.5V$	+25°C		6.5	10	Ω	
(Note 5)	TFLAT(ON)		E			13		
NO or NC Off-Leakage Current	I _{NC(OFF)} or	$\begin{array}{l} I_{NC(OFF)} or \\ I_{NO(OFF)} \end{array} \hspace{0.5cm} V+=+5.5V, \ V-=-5.5V; \\ V_{COM}=+4.5V, \ -4.5V; \\ V_{NO}, \ V_{NC}=-4.5, \ +4.5V \end{array} \hspace{0.5cm} -$	+25°C	-1	0.05	1	nA	
NO OF NO OF-Leakage Current	I _{NO(OFF)}		E	-5		5		
		V+ = +5.5V, V- = -5.5V; V _{COM} = +4.5V, -4.5V;	+25°C	-1	0.05	1	nA	
COM Off-Leakage Current	ICOM(OFF)	$V_{\text{COM}} = +4.5V, -4.5V,$ $V_{\text{NO}}, V_{\text{NC}} = -4.5, +4.5V$	E	-5		5	10.0	
COM On-Leakage Current	$V_{+} = +5.5V, V_{-} = -5.5V, V_{COM} =$	+25°C	-2	0.05	2	nA		
<u>j</u>	ICOM(ON)	+4.5V, -4.5V; V _{NO} , V _{NC} = +4.5V, -4.5V, or unconnected	E	-10		10	1.07	

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Low-Voltage, Dual-Supply, SPDT Analog Switch with Enable

ELECTRICAL CHARACTERISTICS—±5V Supply (continued)

(V+ = +4.5V to +6V, V- = -4.5V to -6V, V_{IH} = +2.4V, V_{IL} = +0.8V, GND = 0, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	ТҮР	МАХ	UNITS
SWITCH DYNAMIC CHARACTI	ERISTICS			I			1
		V _{NO} , V _{NC} = +3V, -3V,	+25°C		40	60	
Turn-On Time	ton	$R_L = 1k\Omega$, $C_L = 35pF$	E			75	ns
T		$V_{NO}, V_{NC} = +3V, -3V,$	+25°C		28	40	1
Turn-Off Time	toff	$R_L = 1k\Omega$, $C_L = 35pF$	E			50	ns
		$V_{\rm NC} = +3V, V_{\rm NO} = -3V,$	+25°C		50	70	
Transition Time	t trans	$V_{NC} = -3V$, $V_{NO} = +3V$, $R_L = 1k\Omega$, $C_L = 35pF$	E			85	ns
Break-Before-Make Time (Note 6)	t _{BBM}	$\label{eq:VNO} \begin{array}{l} V_{NO}, V_{NC} = +3V, -3V, R_{L} = 300\Omega, \\ C_{L} = 35pF \end{array}$	+25°C	5	15		ns
Charge Injection	Q	$V_{\text{GEN}} = 0$, $R_{\text{GEN}} = 0$, $C_{\text{L}} = 100 \text{pF}$	+25°C		3		рС
-3dB Bandwidth	f-3dB	$\begin{aligned} R_L &= 50\Omega, \ C_L = 10 \text{pF}, \\ f_{\text{OdB}} &= 1 \text{MHz} \end{aligned}$	+25°C		450		MHz
Off-Isolation (Note 7)	VISO	$\label{eq:RL} \begin{split} R_L &= 50\Omega, C_L = 10 \text{pF}, \\ f_{\text{IN}} &= 1 \text{MHz} \end{split}$	+25°C		-77		dB
Crosstalk (Control Input to Signal Output)		$ \begin{array}{l} R_L = 50 \Omega, \ C_L = 10 p F, \ V+ = +4.5 V, \\ V- = -4.5 V, \ f_{IN} = 1 M Hz, \ V \overline{EN} = V_{IH} \end{array} $	+25°C		68		mV
Crosstalk (Between Switches)	V _{CT}	$\label{eq:RL} \begin{split} R_L &= 50\Omega, C_L = 10 \text{pF}, \\ f_{\text{IN}} &= 1 \text{MHz} \end{split}$	+25°C		-72		dB
Total Harmonic Distortion	THD	$\label{eq:RL} \begin{array}{l} R_{L} = 600 k \Omega, \ C_{L} = 50 pF, \\ f_{IN} = 20 k Hz \end{array}$	+25°C		0.15		%
Control Input Capacitance	CIN				3		pF
NO or NC Off-Capacitance	COFF	f _{IN} = 1MHz	+25°C		6		pF
COM Off-Capacitance	CCOM(OFF)	f _{IN} = 1MHz	+25°C		8		pF
COM On-Capacitance	CCOM(ON)	f _{IN} = 1MHz	+25°C		14		pF
LOGIC INPUT			1	n			1
Input Voltage Low	VIL					0.8	V
Input Voltage High	VIH			2.4			V
Input Leakage Current	ال	V+ = +5.5V, V- = -5.5V,	+25°C	-1	0.0001	1	μA
	'L	$V_{IN} = V \overline{EN} = 0 \text{ or } +5.5V$	E	-10		10	μ.,
POWER SUPPLY			T	r			r
Power-Supply Range	V+		ļ	2		6	v
	V-			-2		-6	
Positive Supply Current	l+	$V_{+} = +5.5V, V_{-} = -5.5V,$	+25°C	-1	0.0001	1	μA
		$V_{IN} = V \overline{EN} = 0 \text{ or } +5.5V$	E	-10	0.000 /	10	
Negative Supply Current	I-	V+ = +5.5V, V- = -5.5V, V _{IN} = V FN = 0 or +5.5V	+25°C	-1	0.0001	1	μA
		$v_{\rm IN} = v_{\rm EN} = 0.01 + 0.0V$	E	-10		10	

Low-Voltage, Dual-Supply, SPDT Analog Switch with Enable

ELECTRICAL CHARACTERISTICS—Single +5V Supply

(V+ = +4.5V to +6V, V- = 0, V_{IH} = +2.4V, V_{IL} = +0.8V, GND = 0, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	ТҮР	MAX	UNITS
ANALOG SWITCH		•	1				
Analog Signal Range	V _{COM} , V _{NO} , V _{NC}			0		V+	V
On-Resistance	R _{ON}	V+ = +4.5V, V- = 0,	+25°C		72	100	Ω
On-nesistance	NON	$I_{COM} = 1mA; V_{NO}, V_{NC} = +3.5 V$	E			125	52
On-Resistance Match Between	ΔRon	V+ = +4.5V, V- = 0,	+25°C		0.75	5	Ω
Channels (Note 4)		$I_{COM} = 1mA; V_{NO}, V_{NC} = +3.5 V$	E			7	22
SWITCH DYNAMIC CHARACTE	RISTICS						
Turn-On Time	ton	V_{NO} , $V_{NC} = +3V$,	+25°C		62	90	ne
	UN	$R_L = 1k\Omega$, $C_L = 35pF$	Е			125	ns
Turn-Off Time	torr	V_{NO} , $V_{NC} = +3V$,	+25°C		22	60	20
	tOFF	$R_L = 1k\Omega$, $C_L = 35pF$	E			75	ns
Transition Time	TRANS	$V_{NC} = +3V, V_{NO} = 0,$ $V_{NC} = 0, V_{NO} = +3V,$	+25°C		68	100	ns
	TRAINS	$R_{L} = 1k\Omega, C_{L} = 35pF$	E			130	113
Break-Before-Make Time (Note 6)	^t BBM	$\label{eq:VNO} \begin{array}{l} V_{NO}, \ V_{NC} = +3V, \\ R_L = 300\Omega, \ C_L = 35 pF \end{array}$	E	10	35		ns
LOGIC INPUT							
Input Voltage Low	VIL					0.8	V
Input Voltage High	VIH			2.4			V
		V+ = +5.5V, V- = 0,	+25°C	-1	0.0001	1	
Input Leakage Current	١L	$V_{IN} = V \overline{EN} = 0 \text{ or } +5.5V$	E	-10		10	μA
POWER SUPPLY		·					
Power-Supply Range	V+			1.8		12	V
Desitive Cumply Current		V+ = +5.5V, V- = 0,	+25°C	-1	0.0001	1	
Positive Supply Current	1+	$V_{IN} = V \overline{EN} = 0 \text{ or } +5.5V$	E	-10		10	μA
Negative Supply Current	-	V+ = +5.5V, V- = 0,	+25°C	-1	0.0001	1	μA
negative Supply Current	1-	$V_{IN} = V \overline{EN} = 0 \text{ or } +5.5V$	E	-10		10	μΑ

Low-Voltage, Dual-Supply, SPDT Analog Switch with Enable

ELECTRICAL CHARACTERISTICS—Single +3V Supply

(V+ = +2.7V to +3.3V, V- = 0, V_{IH} = +2.4V, V_{IL} = +0.8V, GND = 0, T_A = T_{MIN} to T_{MAX}, unless otherwise noted. Typical values are at T_A = +25°C.) (Notes 2, 3)

PARAMETER	SYMBOL	CONDITIONS	TA	MIN	TYP	МАХ	UNITS
ANALOG SWITCH							
Analog Signal Range	Vcom, V _{NO} , V _{NC}			0		V+	V
On-Resistance	Pou	V + = +2.7V, V - = 0,	+25°C		160	275	Ω
OII-Resistance	RON	$I_{COM} = 1mA; V_{NO}, V_{NC} = +1.5V$	E			300	52
On-Resistance Match Between	ADest	V+ = +2.7V, V- = 0,	+25°C		1.5	10	0
Channels (Note 4)	ΔR_{ON}	$I_{COM} = 1mA; V_{NO}, V_{NC} = +1.5V$	E			12	Ω
SWITCH DYNAMIC CHARACTE	RISTICS						
Turn-On Time	tou	$V_{NO}, V_{NC} = +1.5V,$	+25°C		120	250	20
	ton	$R_L = 2k\Omega$, $C_L = 35pF$	E			275	ns
T 0" T		$V_{NO}, V_{NC} = +1.5V,$	+25°C		40	110	
Turn-Off Time	tOFF	$R_L = 2k\Omega$, $C_L = 35pF$	E			125	ns
Break-Before-Make Time (Note 6)	t _{BBM}	$V_{NO}, V_{NC} = +1.5V,$ $R_L = 2k\Omega, C_L = 35pF$	E	10			ns
LOGIC INPUT							
Input Voltage Low	VIL					0.8	V
Input Voltage High	VIH			2.4			V
	L.	V+ = +3.3V, V- = 0,	+25°C	-1	0.0001	1	
Input Leakage Current	١L	$V_{IN} = V \overline{EN} = 0 \text{ or } +3.3V$	E	-10		10	10 µA

Note 2: The algebraic convention is used in this data sheet; the most negative value is shown in the minimum column.

Note 3: SOT-packaged products are 100% tested at +25°C and guaranteed by design at the full-rated temperature.

Note 4: $\Delta R_{ON} = R_{ON}(MAX) - R_{ON}(MIN)$.

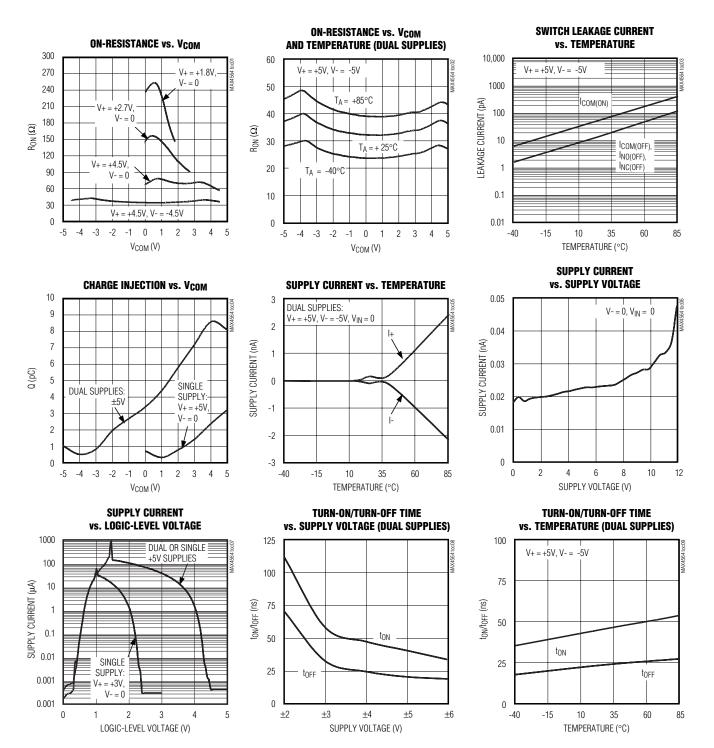
Note 5: Flatness is defined as the difference between the maximum and minimum value of on-resistance as measured over the specified analog signal ranges.

Note 6: Guaranteed by design.

Note 7: Off-Isolation = $20\log_{10} (V_{COM} / V_{NO})$, V_{NO} = input to off switch.

Low-Voltage, Dual-Supply, SPDT Analog Switch with Enable

 $(T_A = +25^{\circ}C, \text{ unless otherwise noted.})$



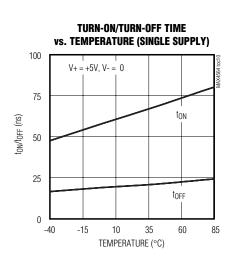
Typical Operating Characteristics

Maxim Integrated

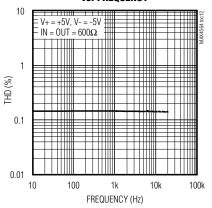
Low-Voltage, Dual-Supply, SPDT Analog Switch with Enable

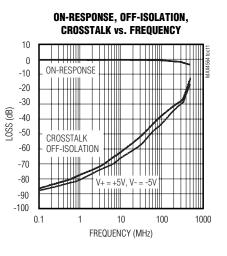
Typical Operating Characteristics (continued)

 $(T_A = +25^{\circ}C, unless otherwise noted.)$

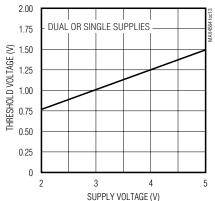


TOTAL HARMONIC DISTORTION vs. FREQUENCY





LOGIC-LEVEL THRESHOLD VOLTAGE vs. supply voltage



Low-Voltage, Dual-Supply, SPDT Analog Switch with Enable

Pin Description

μΜΑΧ	SOT23	NAME	FUNCTION
1	8	СОМ	Analog Switch Common
2	7	ĒN	Device Enable. Drive $\overline{\text{EN}}$ low for normal SPDT switch operation. If $\overline{\text{EN}}$ is high, both NO and NC are disconnected.
3	6	V-	Negative Supply Voltage
4	5	GND	Ground
5	3	IN	Digital Control Input
6	4	NO	Analog Switch Normally Open
7	1	NC	Analog Switch Normally Closed
8	2	V+	Positive Supply Voltage

Detailed Description

The MAX4564 is a dual-supply SPDT CMOS analog switch. The MAX4564 has break-before-make switching. The CMOS switch construction provides Rail-to-Rail[®] signal handling while consuming virtually no power. Each of the two switches is independently controlled by a TTL/CMOS-level-compatible digital input.

Applications Information

Overvoltage Protection

Do not exceed the absolute maximum ratings because stresses beyond the listed ratings may cause permanent damage to the device. Proper power-supply sequencing is recommended for all CMOS devices. Always sequence V+ on first, then V-, followed by the logic inputs NO, NC, or COM. If power-supply sequencing is not possible, add two small-signal diodes (D1, D2) in series with supply pins. Adding diodes reduces the analog signal range to one diode drop below V+ and one diode drop above V-, but does not affect the device's low switch resistance and low leakage characteristics.



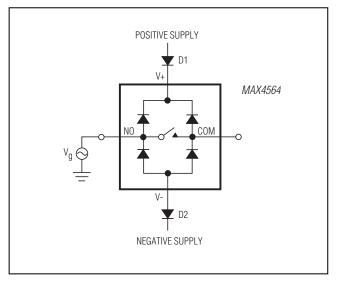


Figure 1. Overvoltage Protection Using Two External Blocking Diodes

Low-Voltage, Dual-Supply, SPDT Analog Switch with Enable

_Test Circuits/Timing Diagrams (continued)

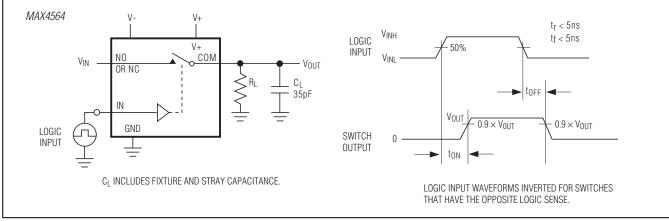


Figure 2. Switching Time

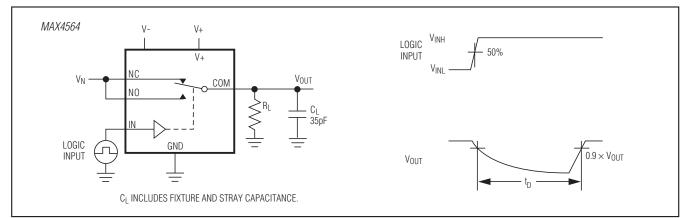


Figure 3. Break-Before-Make Interval

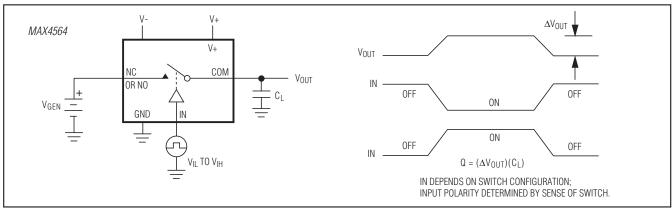


Figure 4. Charge Injection

Low-Voltage, Dual-Supply, SPDT Analog Switch with Enable

_Test Circuits/Timing Diagrams (continued)

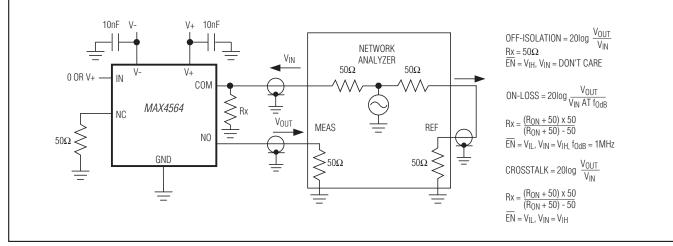


Figure 5. On-Loss, Off-Isolation, and Crosstalk

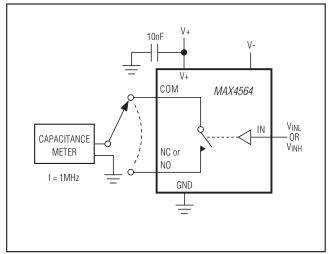


Figure 6. Channel Off/On-Capacitance

Chip Information

PROCESS : CMOS

Package Information

For the latest package outline information and land patterns (footprints), go to <u>www.maximintegrated.com/packages</u>. Note that a "+", "#", or "-" in the package code indicates RoHS status only. Package drawings may show a different suffix character, but the drawing pertains to the package regardless of RoHS status.

PACKAGE TYPE	PACKAGE CODE	OUTLINE NO.	LAND PATTERN NO.
8 SOT23	K8SN+1	<u>21-0078</u>	<u>90-0176</u>
8 SO	U8+1	<u>21-0036</u>	<u>90-0092</u>

Low-Voltage, Dual-Supply, SPDT Analog Switch with Enable

Revision History

REVISION	REVISION	DESCRIPTION	PAGES
NUMBER	DATE		CHANGED
2	10/12	Added lead-free designation to the part numbers in the Ordering Information	1



Maxim Integrated cannot assume responsibility for use of any circuitry other than circuitry entirely embodied in a Maxim Integrated product. No circuit patent licenses are implied. Maxim Integrated reserves the right to change the circuitry and specifications without notice at any time. The parametric values (min and max limits) shown in the Electrical Characteristics table are guaranteed. Other parametric values quoted in this data sheet are provided for guidance.

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